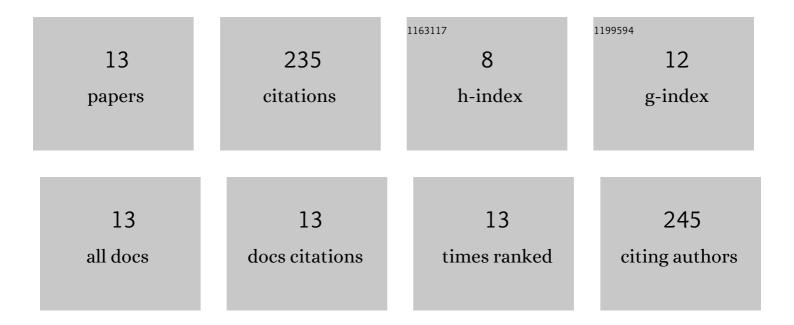
Hyun Kyong Cho

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Impact of operation parameters on the degradation of 233 nm AlGaN-based far-UVC LEDs. Journal of Applied Physics, 2022, 131, .	2.5	17
2	Spectrally pure far-UVC emission from AlGaN-based LEDs with dielectric band pass filters. Journal Physics D: Applied Physics, 2022, 55, 205105.	2.8	3
3	Comparison of Ultraviolet B Lightâ€Emitting Diodes with Single or Triple Quantum Wells. Physica Status Solidi (A) Applications and Materials Science, 2021, 218, 2100100.	1.8	3
4	Skin tolerant inactivation of multiresistant pathogens using far-UVC LEDs. Scientific Reports, 2021, 11, 14647.	3.3	37
5	Milliwatt power 233 nm AlGaN-based deep UV-LEDs on sapphire substrates. Applied Physics Letters, 2020, 117, .	3.3	50
6	Reliability of UVC LEDs fabricated on AlN/sapphire templates with different threading dislocation densities. Applied Physics Letters, 2020, 117, .	3.3	34
7	Low resistance n-contact for UVC LEDs by a two-step plasma etching process. Semiconductor Science and Technology, 2020, 35, 095019.	2.0	7
8	Enhanced wall plug efficiency of AlGaN-based deep-UV LEDs using Mo/Al as p-contact. IEEE Photonics Technology Letters, 2020, , 1-1.	2.5	9
9	Degradation of (In)AlGaN-Based UVB LEDs and Migration of Hydrogen. IEEE Photonics Technology Letters, 2019, 31, 529-532.	2.5	43
10	Bow Reduction of AlInGaN-Based Deep UV LED Wafers Using Focused Laser Patterning. IEEE Photonics Technology Letters, 2018, 30, 1792-1794.	2.5	2
11	Chip design for thin-film deep ultraviolet LEDs fabricated by laser lift-off of the sapphire substrate. Semiconductor Science and Technology, 2017, 32, 12LT01.	2.0	14
12	Highly Reflective p-Contacts Made of Pd-Al on Deep Ultraviolet Light-Emitting Diodes. IEEE Photonics Technology Letters, 2017, 29, 2222-2225.	2.5	14
13	Enhanced light extraction efficiency of UV LEDs by encapsulation with UV-transparent silicone resin. Semiconductor Science and Technology, 0, , .	2.0	2